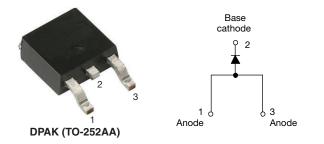
Vishay Semiconductors

High Voltage Surface Mountable Input Rectifier Diode, 8 A



www.vishay.com

| PRIMARY CHARACTERISTICS | | |
|----------------------------------|-----------------|--|
| I _{F(AV)} | 8 A | |
| V _R | 1200 V | |
| V _F at I _F | 1.1 V | |
| I _{FSM} | 150 A | |
| T _J max. | 150 °C | |
| Package | DPAK (TO-252AA) | |
| Circuit configuration | Single | |

FEATURES

- Glass passivated pellet chip junction
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Flexible solution for reliable AC power rectification
- $\bullet\,$ High surge, low V_F rugged blocking diode for DC charging stations
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- · On-board and off-board EV / HEV battery chargers
- Renewable energy inverters

DESCRIPTION

The VS-8EWS12SLHM3 rectifier high voltage series has been optimized for very low forward voltage drop, with moderate leakage.

The **high reverse voltage** range available allows design of input stage primary rectification with **outstanding voltage surge** capability.

| OUTPUT CURRENT IN TYPICAL APPLICATIONS | | | | |
|---|---------------------|--------------------|-------|--|
| APPLICATIONS | SINGLE-PHASE BRIDGE | THREE-PHASE BRIDGE | UNITS | |
| NEMA FR-4 or G10 glass fabric-based epoxy with 4 oz. (140 $\mu m)$ copper | 1.2 | 1.6 | | |
| Aluminum IMS, R _{thCA} = 15 °C/W | 2.5 | 2.8 | A | |
| Aluminum IMS with heatsink, $R_{thCA} = 5 \text{ °C/W}$ | 5.5 | 6.5 | | |

Note

• $T_A = 55 \text{ °C}, T_J = 125 \text{ °C}, \text{ footprint } 300 \text{ mm}^2$

| MAJOR RATINGS AND CHARACTERISTICS | | | |
|-----------------------------------|-----------------------------|-------------|-------|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS |
| I _{F(AV)} | Sinusoidal waveform | 8 | А |
| V _{RRM} | | 1200 | V |
| I _{FSM} | | 150 | A |
| V _F | 8 A, T _J = 25 °C | 1.10 | V |
| TJ | | -55 to +150 | °C |

| VOLTAGE RATINGS | | | |
|-----------------|---|---|-------------------------------------|
| PART NUMBER | V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | I _{RRM} AT 150 °C mA |
| VS-8EWS12SLHM3 | 1200 | 1300 | 0.50 |

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 1
 Document Number: 96118

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COMPLIANT HALOGEN



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| ABSOLUTE MAXIMUM RATINGS | | | | |
|--|--------------------|--|--------|------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Maximum average forward current | I _{F(AV)} | T_C = 105 °C, 180° conduction half sine wave | 8 | |
| Maximum peak one cycle | 1 | 10 ms sine pulse, rated V _{RRM} applied | 125 | А |
| non-repetitive surge current | I _{FSM} | 10 ms sine pulse, no voltage reapplied | 150 | |
| Maximum I ² t for fusing I ² t | l ² t | 10 ms sine pulse, rated V _{RRM} applied | 78 | A ² s |
| Maximum - t for fusing | 1-1 | 10 ms sine pulse, no voltage reapplied | 110 | A-5 |
| Maximum I ² √t for fusing | l²√t | t = 0.1 ms to 10 ms, no voltage reapplied | 1100 | A²√s |

| ELECTRICAL SPECIFICATIONS | | | | | |
|---------------------------------|-------------------------|---|---|--------|-------|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | VALUES | UNITS |
| Maximum forward voltage drop | V _{FM} | 8 A, T _J = 25 °C | | 1.1 | V |
| Forward slope resistance | r _t | T.I = 150 °C | | 20 | mΩ |
| Threshold voltage | V _{F(TO)} | 1j = 150°C | | 0.82 | V |
| Maximum reverse leakage current | 1 | $T_J = 25 \text{ °C}$ $V_B = \text{rated } V_{BBM}$ | \mathcal{V}_{-} roted \mathcal{V}_{-} | 0.05 | mA |
| Maximum reverse leakage current | T _J = 150 °C | $v_{\rm R} = rate v_{\rm RRM}$ | 0.50 | ШA | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | |
|--|-----------------------------------|----------------------------|-------------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -55 to +150 | °C |
| Maximum thermal resistance, junction to case | R _{thJC} | DC operation | 2.5 | °C/W |
| Typical thermal resistance, junction to ambient (PCB mount) | R _{thJA} ⁽¹⁾ | | 62 | C/W |
| Approvimate weight | | | 1 | g |
| Approximate weight | | | 0.03 | oz. |
| Marking device | | Case style DPAK (TO-252AA) | 8EWS | 12SH |

Note

(1) When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W

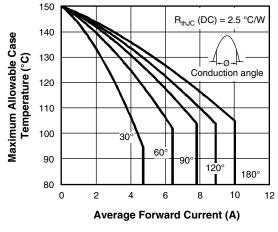


Fig. 1 - Current Rating Characteristics

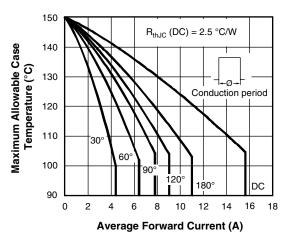


Fig. 2 - Current Rating Characteristics

2

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VS-8EWS12SLHM3

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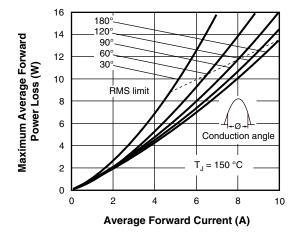


Fig. 3 - Forward Power Loss Characteristics

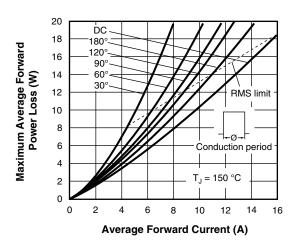
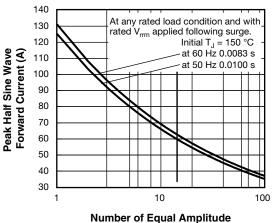


Fig. 4 - Forward Power Loss Characteristics



Half Cycle Current Pulses (N)

Fig. 5 - Maximum Non-Repetitive Surge Current

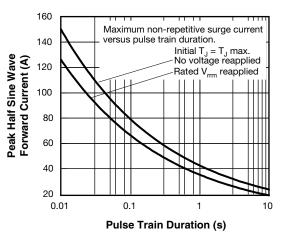
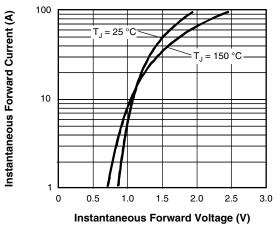


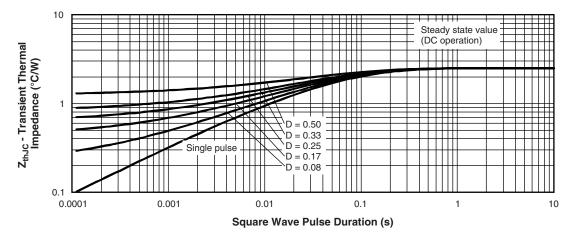
Fig. 6 - Maximum Non-Repetitive Surge Current





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Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE Device code VS-S S 8 Ε w 12 L н М3 (5)2) (3) (6)7 1 4 8 9 (10)Vishay Semiconductors product 2 Current rating (8 = 8 A)-3 Circuit configuration: E = single 4 Package: _ W = DPAK (TO-252AA) 5 Type of silicon: _ S = standard recovery rectifier Voltage code x 100 = V_{RRM} — 12 = 1200 V 6 -S = surface mountable 7 -8 L = tape and reel (left oriented), for different orientation contact factory _ 9 H = AEC-Q101 qualified -10 Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

| ORDERING INFORMATION (Example) | | | | |
|--------------------------------|------------------|------------------------|-----------------------|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | |
| VS-8EWS12SLHM3 | 3000 | 3000 | 13" diameter reel | |

| LINKS TO RELATED DOCUMENTS | | |
|----------------------------|--------------------------|--|
| Dimensions | www.vishay.com/doc?95519 | |
| Part marking information | www.vishay.com/doc?95518 | |
| Packaging information | www.vishay.com/doc?96495 | |
| SPICE model | www.vishay.com/doc?96668 | |

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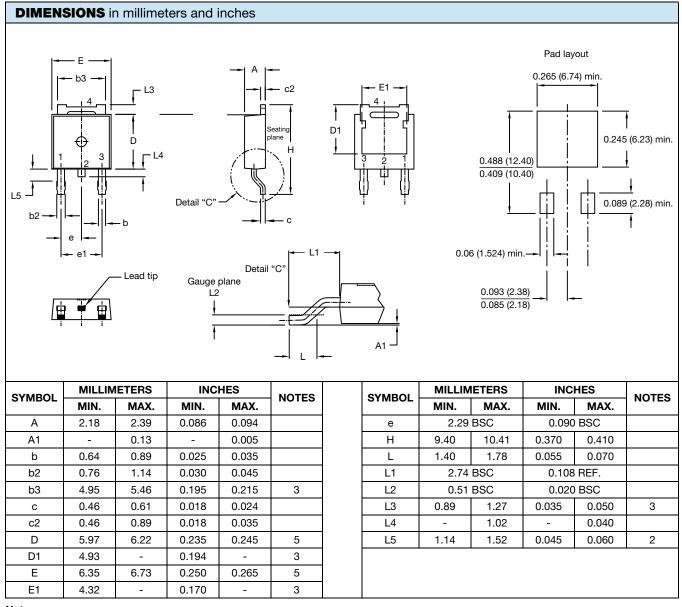
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Outline Dimensions



Vishay Semiconductors

DPAK (TO-252AA)



Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Dimensions D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁵⁾ Outline conforms to JEDEC[®] outline TO-252AA, except for D1 dimension



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